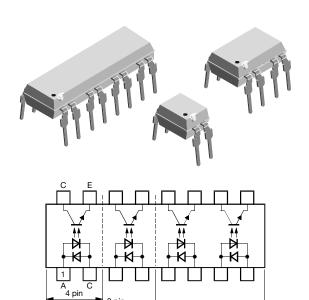


Optocoupler, Phototransistor Output, AC Input



LINKS TO ADDITIONAL RESOURCES







R R

16 pin



DESCRIPTION

The K814P, K824P, K844P consist of a phototransistor optically coupled to 2 gallium arsenide infrared emitting diodes (reverse polarity) in 4 pin (single); 8 pin (dual) or 16-pin (quad) plastic dual inline package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

FEATURES

- Endstackable to 2.54 mm (0.1") spacing
- DC isolation test voltage V_{ISO} = 5000 V_{RMS}
- Low coupling capacitance of typical 0.3 pF
- Current transfer ratio (CTR) of typical 100 %
- Low temperature coefficient of CTR
- Wide ambient temperature range
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

Pb-free e3



APPLICATIONS

- Feature phones
- Answering machines
- PBX
- Fax machines

AGENCY APPROVALS

- UL
- cUL
- CQC

ORDERING INFORMATION DIP-# 4 Κ 8 # Ρ PART NUMBER **AGENCY CERTIFIED / PACKAGE CTR (%)** UL, cUL > 20 DIP-4, single channel K814P DIP-8, dual channel K824P DIP-16, quad channel K844P



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Forward current		I _F	60	mA			
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α			
Power dissipation		P _{diss}	100	mW			
Junction temperature		Tj	125	°C			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA			
Power dissipation		P _{diss}	150	mW			
Junction temperature		Tj	125	°C			
COUPLER							
AC isolation test voltage (RMS)	t = 1.0 min	V _{ISO}	5000	V _{RMS}			
Total power dissipation		P _{tot}	250	mW			
Operating ambient temperature range		T _{amb}	-40 to +100	°C			
Storage temperature range		T _{stg}	-55 to +125	°C			
Soldering temperature (1)	2 mm from case, t ≤ 10 s	T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 50 mA	V_{F}	-	1.25	1.6	V	
Reverse current	V _R = ± 6 V	I _R	-	-	10	μA	
OUTPUT							
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	70	-	-	V	
Emitter collector breakdown voltage	I _E = 10 μA	BV _{ECO}	7	-	-	V	
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}	-	-	100	nA	
COUPLER							
Collector emitter saturation voltage	$I_F = \pm 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}	-	-	0.3	V	
Cut-off frequency	$I_F = \pm 10$ mA, $V_{CE} = 5$ V, $R_L = 100$ Ω	f _c	-	100	-	kHz	
Coupling capacitance	f = 1 MHz	C _k	-	0.3	-	pF	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$	K814P	CTR	20	-	300	%



SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	t _d	-	3	-	μs
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	t _r	-	3	-	μs
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	t _f	-	4.7	-	μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	ts	-	0.3	-	μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	t _{on}	-	6	-	μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see Fig. 1)}$	t _{off}	-	5	-	μs
Turn-on time	$V_S = 5 \text{ V}, I_C = 10 \text{ mA}, R_L = 1 \text{ k}\Omega \text{ (see Fig. 1)}$	t _{on}	-	9	-	μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 10 \text{ mA}, R_L = 1 \text{ k}\Omega \text{ (see Fig. 1)}$	t _{off}	-	18	-	μs

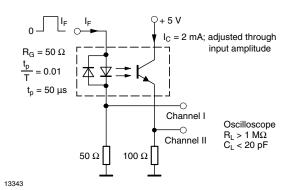


Fig. 1 - Test Circuit, Non-Saturated Operation

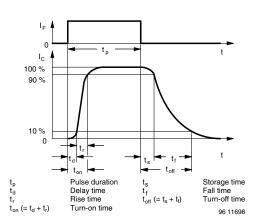


Fig. 3 - Switching Times

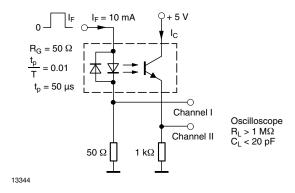


Fig. 2 - Test Circuit, Saturated Operation

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

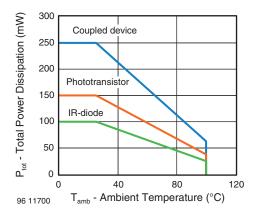


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

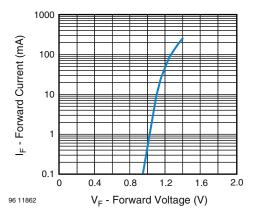


Fig. 5 - Forward Current vs. Forward Voltage

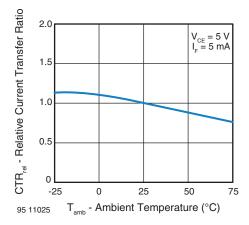


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

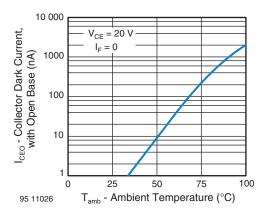


Fig. 7 - Collector Dark Current vs. Ambient Temperature

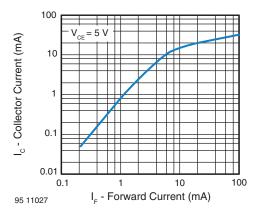


Fig. 8 - Collector Current vs. Forward Current

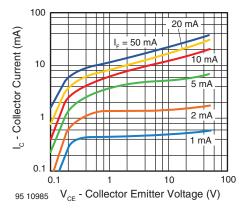


Fig. 9 - Collector Current vs. Collector Emitter Voltage

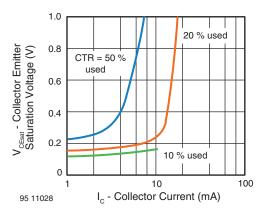


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

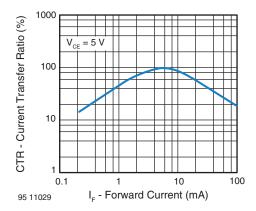


Fig. 11 - Current Transfer Ratio vs. Forward Current

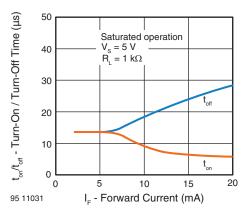


Fig. 12 - Turn-on / Turn-off Time vs. Forward Current

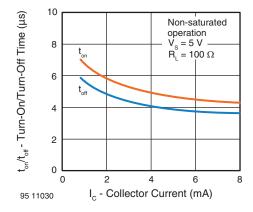
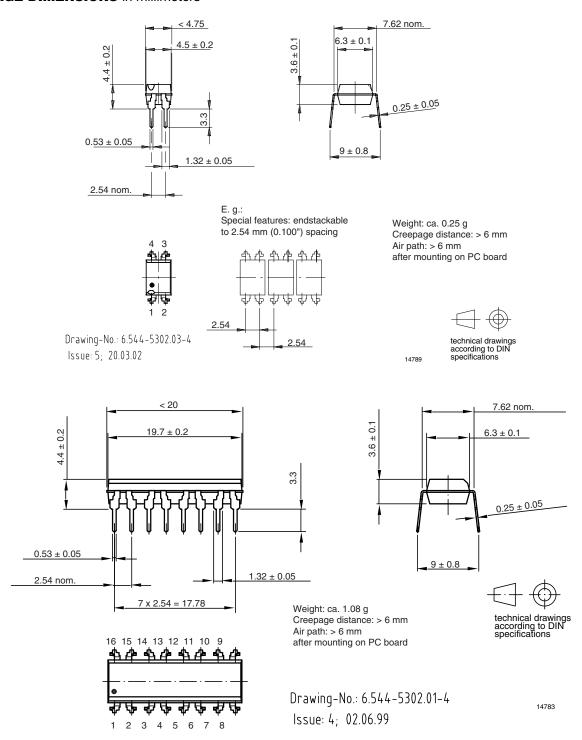


Fig. 13 - Turn-on / Turn-off Time vs. Collector Current



PACKAGE DIMENSIONS in millimeters



7.62 nom.

 6.3 ± 0.1

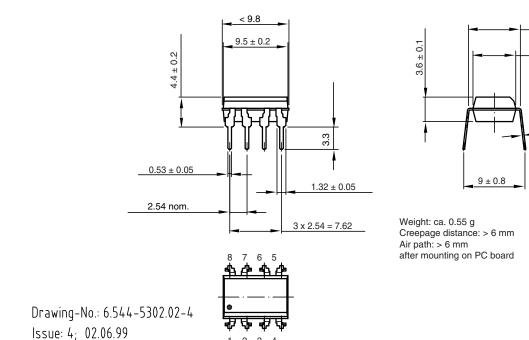
 0.25 ± 0.05

technical drawings according to DIN specifications

14784

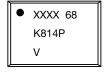


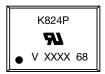
Vishay Semiconductors

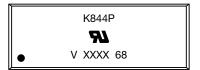


3

PACKAGE MARKING (example)







Note

• XXXX = LMC (lot marking code)



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Vishay

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